

Data sheet acquired from Harris Semiconductor SCHS098D - Revised October 2003

# CD40107B Types

# **CMOS Dual 2-input** NAND Buffer/Driver

High-Voltage Type (20-Volt Rating)

The CD40107B is a dual 2-input NAND buffer/driver containing two independent 2-input NAND buffers with open-drain single n-channel transistor outputs. This device features a wired-OR capability and high output sink current capability (136 mA typ. at  $V_{\mbox{DD}}$  = 10 V,  $V_{\mbox{DS}}$  = 1 V). The CD40107B is supplied in 8-lead hermetic dual-in-line ceramic packages (F3A suffix), 8-lead dual-in-line plastic packages (E suffix), 8-lead small-outline packages (M, M96, MT, and PSR suffixes), and 8-lead thin shrink small-outline packages (PW and PWR suffixes).

#### Features:

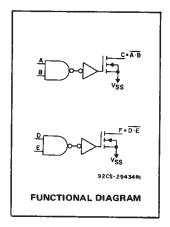
- 32 times standard B-Series output current drive sinking capability - 136 mA typ. @ VDD = 10 V, VDS = 1 V
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 µA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- 5-V, 10-V, and 15-V parametric ratings
- Noise margin, full package temperature range, R<sub>L</sub> to V<sub>DD</sub> = 10 k $\Omega$ :

1 V at V<sub>DD</sub> = 5 V

2 V at V<sub>DD</sub> = 10 V

2.5 V at V<sub>DD</sub> = 15 V

\* Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"



#### **Applications**

- Driving relays, lamps, LEDs
- Line driver
- Level shifter (up or down)

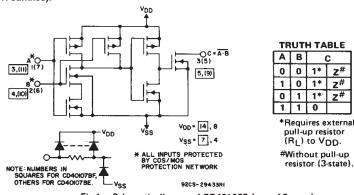


Fig.1 - Schematic diagram of CD40107B (one of 2 gates)

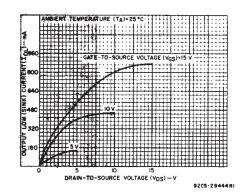


Fig.2 - Typical output low (sink) current characteristics.

### MAXIMUM RATINGS, Absolute-Maximum Values:

DO SUFFET-VOLTAGE NANGE, (VDD)
Voltages referenced to VSS Terminal)0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS0.5V to VDD +0.5V
DC INPUT CURRENT, ANY ONE INPUT ±10mA
POWER DISSIPATION PER PACKAGE (PD):
For T <sub>A</sub> = -55°C to +100°C
For T <sub>A</sub> = +100°C to +125°C Derate Linearity at 12mW/°C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW
OPERATING-TEMPERATURE RANGE (T <sub>A</sub> )55°C to +125°C
STORAGE TEMPERATURE RANGE (T <sub>stg</sub> )65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):

At distance 1/16  $\pm$  1/32 inch (1.59  $\pm$  0.79mm) from case for 10s max ...... +265°C

### RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LII		
CHARACTERISTIC	MIN.	MAX.	UNITS
Supply-Voltage Range (For TA=			
Full Package-Temperature Range)	3	18	V

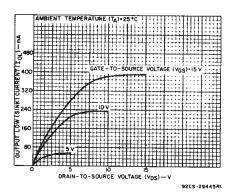


Fig.3 - Minimum output low (sink) current characteristics.

# CD40107B Types

# DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^{\circ}$ C, $C_L = 50$ pF, input $t_r, t_f = 20$ ns

	TEST CONDIT	TIONS	LIMITS			
CHARACTERISTIC		V <sub>DD</sub> Volts	Тур.	Max.	UNITS	
Propagation Delay:		5	100	200		
High-to-Low, tpHL	R <sub>L</sub> * = 120 Ω	10	45	90	ns	
		15	30	60	1	
Low-to-High, tpLH		5	100	200	ns	
	RL* = 120 Ω	10	60	120		
		15	50	100		
Transition Time:		5	50	100	ns	
Transition Time: High-to-Low, t <sub>THL</sub>	RL* = 120 Ω	10	20	40		
		15	10	20		
Low-to-High, t <sub>TLH</sub>		5	50	100	ns	
	RL* = 120 Ω	10	35	70		
		15	25	50	1	
Average Input Capacitance, CIN	Any Input		5 .	7.5	pF	
Average Output Capacitance, COUT	Any Output		30	_	pF	

<sup>\*</sup> R<sub>L</sub> is external pull-up resistor to V<sub>DD</sub>.

#### STATIC ELECTRICAL CHARACTERISTICS

CHARACTER-	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)						UNITS	
13110	Vo	VO VIN V							+25		
	(V)	(V)	(V)	-55	<b>-40</b>	+85	+125	Min.	Тур.	Max.	
Quiescent Device	_	0,5	5	1	1	30	30	_	0.02	1	
Current		0,10	10	2	2	60	60	_	0.02	2	١.
IDD Max.		0,15	15	4	4	120	120	_	0.02	4	μΑ
	_	0,20	20	20	20	600	600	_	0.04	20	
Output Low	0.4	0,5	5	21	20	14	12	16	32	_	
(Sink) Current	1	0,5	5	44	42	30	25	34	68	_	mA
IOL Min.	0.5	0,10	10	49	46	32	28	37	74	_	
- OL	1	0,10	10	89	85	60	51	68	136		
	0.5	0,15	15	66	63	44	38	50	100	-	
Output High (Source) Current IOH Min.	No Internal Pull-Up Device										
Input Low	4.5	-	5		1	.5		: -	_	1.5	
Voltage	9	-	10		,	3		_	-	3	
VIL Max.*	13.5	_	15		4	1		-	_	4	v
Input High	0.5,4.5	_	5		3.5			3.5	_	_	v
Voltage	1,9	_	10		7			7	_		
VIH Min.*	1.5,13.5	1	15	11				11	-	_	
Input Current IJN Max.		0,18	18	±0.1	±0.1	±1	±1	-	±10 <sup>-5</sup>	±0.1	μΑ
Output Leakage Current IOZ Max.	18	0,18	18	2	2	20	20	-	10 <sup>-4</sup>	2	μΑ

<sup>\*</sup> Measured with external pull-up resistor, RL = 10 k $\Omega$  to VDD.

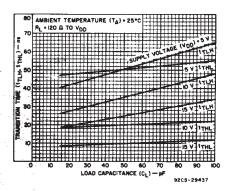


Fig.4 — Typical transition time as a function of load capacitance.

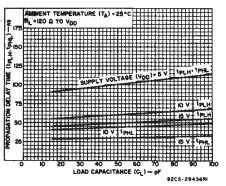


Fig.5 — Typical propagation delay time as a function of load capacitance.

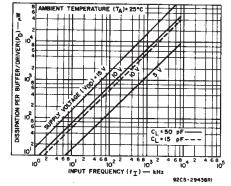


Fig.6 — Typical power dissipation as a function of input frequency.

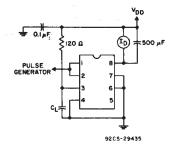
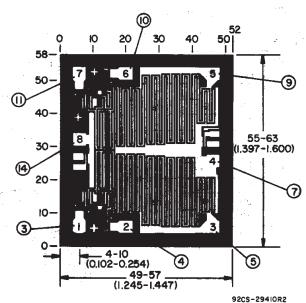


Fig. 7 — Power-dissipation test circuit for CD401078E.

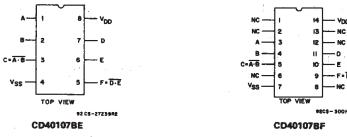
# CD40107B Types



NOTE: NOS. IN PADS FOR CD40107BE NOS. OUTSIDE CHIP FOR CD40107BF

Dimensions and Pad Layout for CD401078H.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10<sup>-3</sup> inch).



**TERMINAL ASSIGNMENTS** 

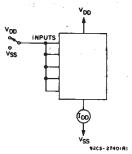


Fig.8 - Quiescent-device current test circuit.

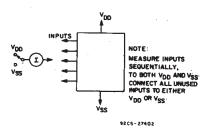


Fig. 9 - Input-current test circuit.

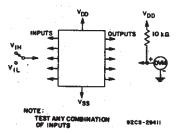


Fig. 10 — Input-voltage test circuit.

#### Special Considerations for CD40107B

Limiting Capacitive Currents for CL > 500 pF, V<sub>DD</sub> > 15 V.
 For V<sub>DD</sub> > 15 V, and load capacitance

For VDD > 15 V, and load capacitance (CL) from output to ground > 500 pF, an external 25  $\Omega$  series limiting resistor should be inserted between the output terminal and CL. No external resistor is necessary if CL < 500 pF or VDD < 15 V.

#### 2. Driving Inductive Loads

When using the CD40107B to drive inductive loads, the load should be shunted with a diode to prevent high voltages from developing across the CD40107B output.

#### PACKAGE OPTION ADDENDUM



i.com 30-May-2005

#### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	n MSL Peak Temp <sup>(3)</sup>
CD40107BE	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD40107BF	ACTIVE	CDIP	J	14	1	TBD	Call TI	Level-NC-NC-NC
CD40107BF3A	ACTIVE	CDIP	J	14	1	TBD	Call TI	Level-NC-NC-NC
CD40107BM	ACTIVE	SOIC	D	8	75	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD40107BM96	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD40107BM96E4	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD40107BME4	ACTIVE	SOIC	D	8	75	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD40107BMT	ACTIVE	SOIC	D	8	250	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD40107BMTE4	ACTIVE	SOIC	D	8	250	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD40107BPSR	ACTIVE	SO	PS	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD40107BPSRE4	ACTIVE	SO	PS	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD40107BPW	ACTIVE	TSSOP	PW	8	150	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
CD40107BPWE4	ACTIVE	TSSOP	PW	8	150	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
CD40107BPWR	ACTIVE	TSSOP	PW	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
CD40107BPWRE4	ACTIVE	TSSOP	PW	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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# **PACKAGE OPTION ADDENDUM**

30-May-2005

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# 14 LEADS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

### P (R-PDIP-T8)

#### PLASTIC DUAL-IN-LINE



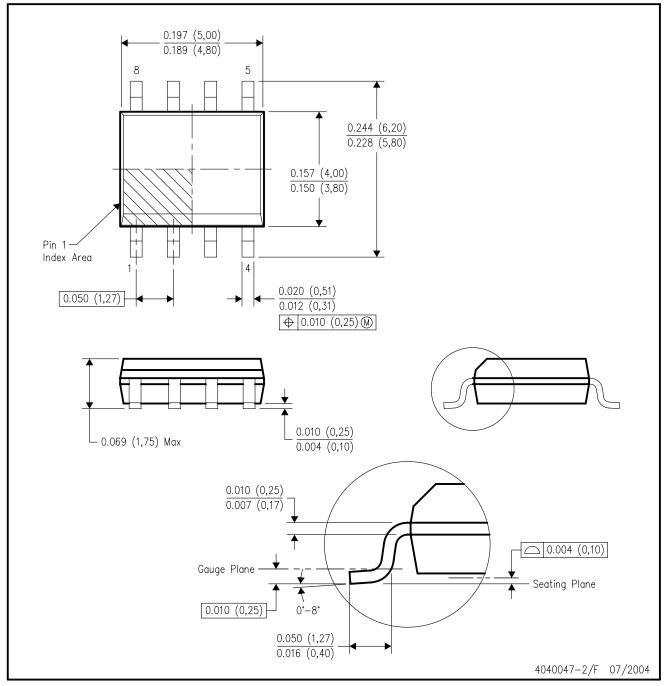
NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001

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# D (R-PDSO-G8)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AA.





NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



# PW (R-PDSO-G\*\*)

#### 14 PINS SHOWN

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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